Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (Ultra-High-Speed U-MOSIII)

TK60D08J1

Switching Regulator Application

· High-Speed switching

• Small gate charge: Q_g = 86 nC (typ.)

• Low drain-source ON resistance: $R_{DS (ON)} = 6.2 \text{ m}\Omega \text{ (typ.)}$

• High forward transfer admittance: |Y_{fs}| = 120 S (typ.)

• Low leakage current: I_{DSS} = 10 μA (max) (V_{DS} = 75 V)

• Enhancement-mode: V_{th} = 1.1 to 2.3 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit	
Drain-source voltage			V_{DSS}	75	V	
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)			V_{DGR}	75	V	
Gate-source voltage			V_{GSS}	±20	٧	
Drain current	DC	(Note 1)	I _D	60	А	
	Pulse	(Note 1)	I _{DP}	240	A	
Drain power dissipation (Tc = 25°C)			P_{D}	140	W	
Single pulse avalanche energy (Note 2)			E _{AS}	498	mJ	
Avalanche current			I _{AR}	60	Α	
Repetitive avalanche energy (Note 3)			E _{AR}	9.2	mJ	
Channel temperature			T _{ch}	150	°C	
Storage temperature range			T _{stg}	-55 to 150	°C	

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2-10V1A

Weight: 1.35 g (typ.)

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Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	0.89	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	83.3	°C/W

Note 1: Ensure that the channel & lead temperature does not exceed 150°C.

Note 2: $V_{DD} = 25 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$, $L = 200 \ \mu\text{H}$, $I_{AR} = 60 \ \text{A}$, $R_G = 1 \Omega$

Note 3: Repetitive rating; pulse width limited by maximum channel temperature.

This transistor is an electrostatic sensitive device. Handle with care.

Internal Connection



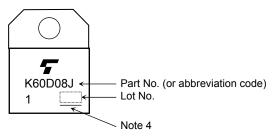
Electrical Characteristics (Ta = 25°C)

Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curi	rent	I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Drain cut-OFF cu	rrent	I _{DSS}	V _{DS} = 75 V, V _{GS} = 0 V	_	_	10	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	75	_	_	V
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	60	_	_	
Gate threshold vo	ltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	1.1	_	2.3	V
Drain-source ON resistance		R _{DS} (ON)	$V_{GS} = 4.5 \text{ V}, I_D = 30 \text{A}$	_	7.1	9.3	- mΩ
			V _{GS} = 10 V, I _D = 30A	_	6.2	7.8	
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 30 A	60	120		S
Input capacitance		C _{iss}		_	5450		pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 10V, V_{GS} = 0 V, f = 1 MHz$		320		
Output capacitance		C _{oss}		_	1260	_	
Switching time	Rise time	t _r	V_{GS} 0 V V_{GS} 0 V 0	_	5	_	ns
	Turn-ON time	t _{on}		_	20	_	
	Fall time	t _f		_	15		
	Turn-OFF time	t _{off}		_	96		
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \simeq 60 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 60 \text{A}$	_	48	_	
			$V_{DD} \simeq 60 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 60 \text{A}$		86		nC
Gate-source charge 1		Q _{gs1}			16		
Gate-drain ("miller") charge		Q _{gd}	$V_{DD} \approx 60 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 60 \text{A}$		20		
Gate switch charge		Q _{SW}		_	27	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I_{DR}	_	_	_	60	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	240	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 60 A, V _{GS} = 0 V	_	-0.9	-1.2	٧
Reverse recovery time	t _{rr}	$I_{DR} = 60 \text{ A}, V_{GS} = 0 \text{ V},$	_	63	_	ns
Reverse recovery charge	Qrr	dI _{DR} /dt = 50 A/μs	_	63	_	nC

Marking

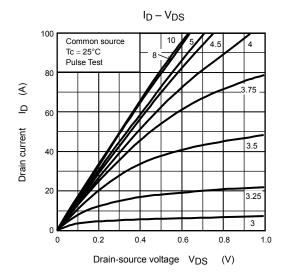


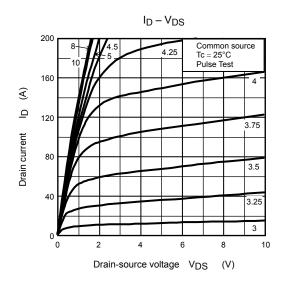
Note 4: A line under a Lot No. identifies the indication of product Labels.

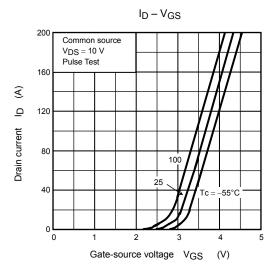
Not underlined: [[Pb]]/INCLUDES > MCV

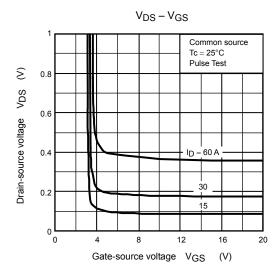
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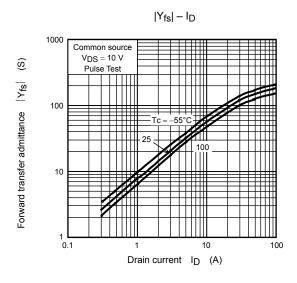
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

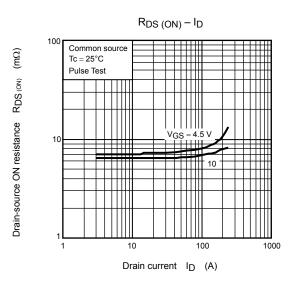


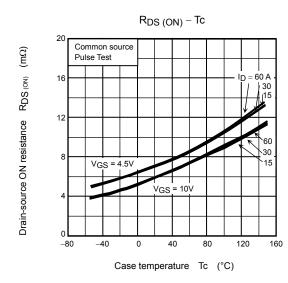


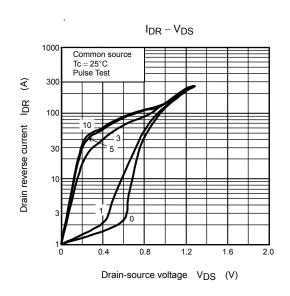


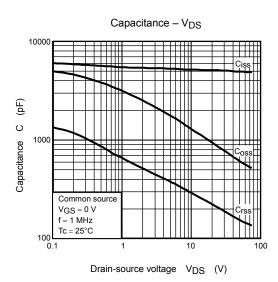


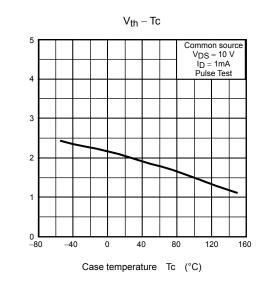


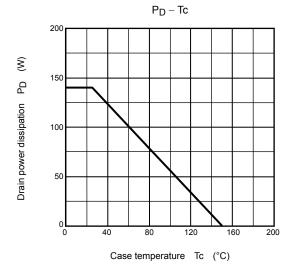


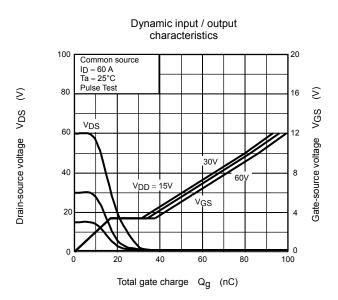






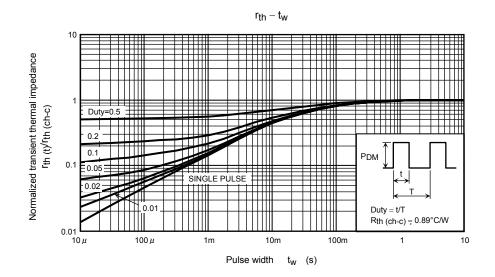




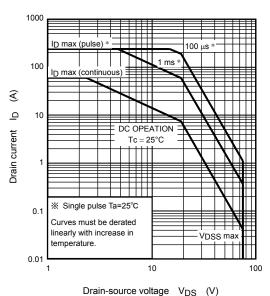


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Gate threshold voltage Vth







EAS - T_{ch}

500

400

300

200

25

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75

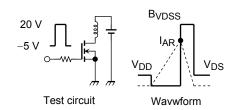
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Channel temperature (initial)

T_{ch} (°C)



$$\begin{aligned} &R_G = 1\Omega \\ &V_{DD} = 25 \text{ V, L} = 200 \text{ } \mu\text{H} \end{aligned} \qquad \text{EAS} = \frac{1}{2} \cdot \text{L} \cdot \text{I}^2 \cdot \left(\frac{\text{BVDSS}}{\text{BVDSS} - \text{V}_{DD}} \right)$$

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